



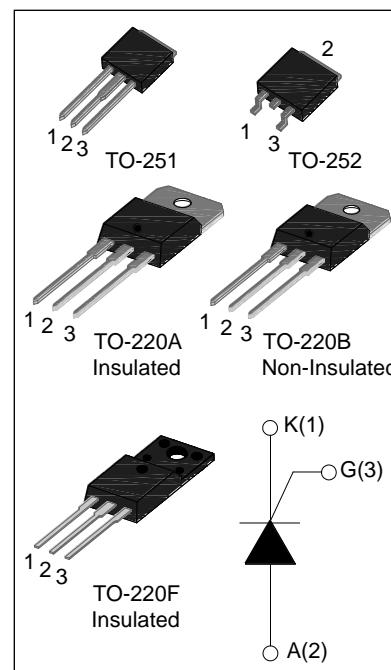
## JCT616/816 Series 16A SCRs

Rev.3.0

**DESCRIPTION:**

JCT616/816 series of silicon controlled rectifiers, with high ability to withstand the shock loading of large current, provide high dv/dt rate with strong resistance to electromagnetic interference. They are especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc.

JCTx16A provides insulation voltage rated at 2500V RMS and JCTx16F provides insulation voltage rated at 2000V RMS from all three terminals to external heatsink. JCTx16A/JCTx16F series comply with UL standards (File ref: E252906).

**MAIN FEATURES**

| Symbol            | JCT616 | JCT816             |
|-------------------|--------|--------------------|
| $V_{DRM}/V_{RRM}$ | 600V   | 800V               |
| $I_{T(RMS)}$      | 16A    |                    |
| $I_{GT}$          |        | $\leq 15\text{mA}$ |

**ABSOLUTE MAXIMUM RATINGS**

| Parameter   | Symbol       | Value           | Unit |
|---|--------------|-----------------|------|
| Storage junction temperature range                          | $T_{stg}$    | -40-150         | °C   |
| Operating junction temperature range                        | $T_j$        | -40-125         | °C   |
| Repetitive peak off-state voltage( $T_j=25^\circ\text{C}$ ) | $V_{DRM}$    | 600/800         | V    |
| Repetitive peak reverse voltage( $T_j=25^\circ\text{C}$ )   | $V_{RRM}$    | 600/800         | V    |
| Non repetitive surge peak Off-state voltage                 | $V_{DSM}$    | $V_{DRM} + 100$ | V    |
| Non repetitive peak reverse voltage                         | $V_{RSM}$    | $V_{RRM} + 100$ | V    |
| RMS on-state current  | $I_{T(RMS)}$ | 16              | A    |
| TO-251 /TO-252<br>( $T_c=103^\circ\text{C}$ )               |              | 16              | A    |
| TO-220A(Ins)<br>( $T_c=85^\circ\text{C}$ )                  |              |                 |      |

|   |   |                     |     |                  |
|---|---|---------------------|-----|------------------|
| RMS on-state current  | TO-220B(Non-Ins)<br>(T <sub>C</sub> =110°C)<br>TO-220F(Ins)<br>(T <sub>C</sub> =90°C) | I <sub>T(RMS)</sub> | 16  | A                |
| Non repetitive surge peak on-state current<br>(tp=10ms)                           |   | I <sub>TSM</sub>    | 190 | A                |
| I <sup>2</sup> t value for fusing (tp=10ms)                                       |   | I <sup>2</sup> t    | 180 | A <sup>2</sup> s |
| Critical rate of rise of on-state current<br>(I <sub>G</sub> =2×I <sub>GT</sub> ) |   | dI/dt               | 50  | A/μs             |
| Peak gate current   |   | I <sub>GM</sub>     | 4   | A                |
| Average gate power dissipation  |   | P <sub>G(AV)</sub>  | 1   | W                |
| Peak gate power   |   | P <sub>GM</sub>     | 5   | W                |

**ELECTRICAL CHARACTERISTICS** (T<sub>j</sub>=25°C unless otherwise specified)

| Symbol          | Test Condition   | Value |      |      | Unit |
|-----------------|--|-------|------|------|------|
|                 |  | MIN.  | TYP. | MAX. |      |
| I <sub>GT</sub> | V <sub>D</sub> =12V R <sub>L</sub> =33Ω                                      | -     | -    | 15   | mA   |
| V <sub>GT</sub> |  | -     | -    | 1.3  | V    |
| V <sub>GD</sub> | V <sub>D</sub> =V <sub>DRM</sub> T <sub>j</sub> =125°C R <sub>L</sub> =3.3KΩ | 0.2   | -    | -    | V    |
| I <sub>L</sub>  | I <sub>G</sub> =1.2I <sub>GT</sub>   | -     | -    | 60   | mA   |
| I <sub>H</sub>  | I <sub>T</sub> =500mA  | -     | -    | 40   | mA   |
| dV/dt           | V <sub>D</sub> =2/3V <sub>DRM</sub> Gate Open T <sub>j</sub> =125°C          | 500   | -    | -    | V/μs |

**STATIC CHARACTERISTICS**

| Symbol           | Parameter   |                       | Value(MAX) | Unit |
|------------------|---|-----------------------|------------|------|
| V <sub>TM</sub>  | I <sub>TM</sub> =32A tp=380μs                                     | T <sub>j</sub> =25°C  | 1.6        | V    |
| I <sub>DRM</sub> | V <sub>D</sub> =V <sub>DRM</sub> V <sub>R</sub> =V <sub>RRM</sub> | T <sub>j</sub> =25°C  | 5          | μA   |
| I <sub>RRM</sub> |   | T <sub>j</sub> =125°C | 2          | mA   |

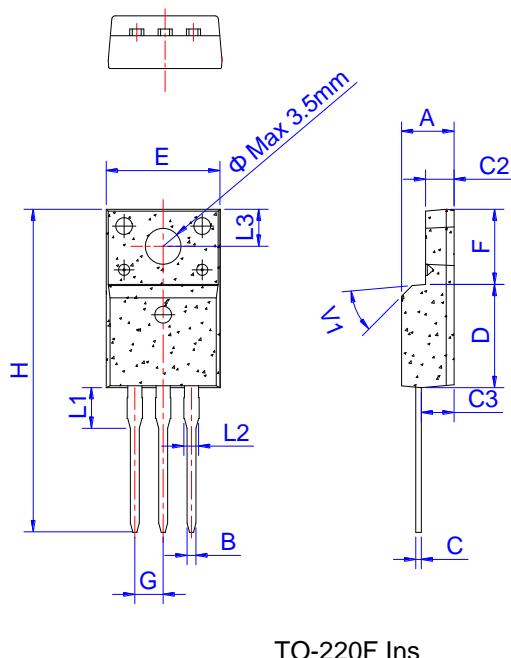
## THERMAL RESISTANCES

| Symbol        | Parameter            | Value            | Unit |
|---------------|----------------------|------------------|------|
| $R_{th(j-c)}$ | junction to case(AC) | TO-220A(Ins)     | 2.3  |
|               |                      | TO-220B(Non-Ins) | 1.1  |
|               |                      | TO-220F(Ins)     | 2.1  |
|               |                      | TO-251/ TO-252   | 1.4  |

## ORDERING INFORMATION

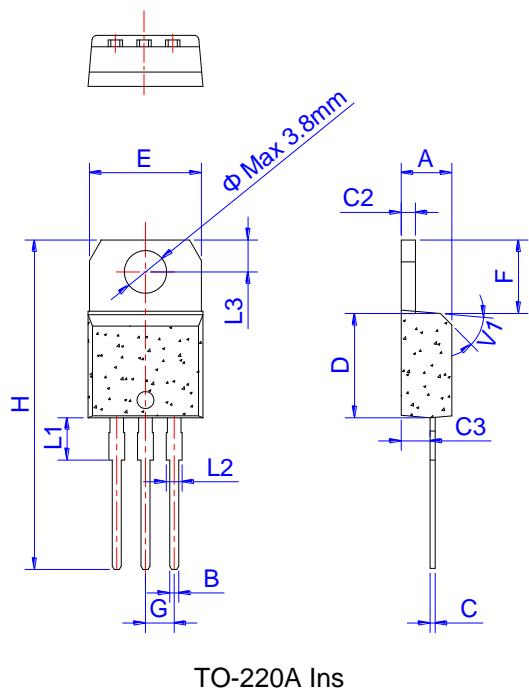
|                                 |      |  |    |                          |
|---------------------------------|------|--|----|--------------------------|
| J                               | CT   | 6  | 16 | B                        |
| JieJie Microelectronics Co.,Ltd |      |  |    | A:TO-220A(Ins)           |
|                                 |      |  |    | F:TO-220F(Ins)           |
|                                 | SCRs |  |    | B:TO-220B(Non-Ins)       |
|                                 |      |  |    | H:TO-251 K:TO-252        |
|                                 |      | 6:V <sub>DRM</sub> /V <sub>RRM</sub> ≥600V |    | I <sub>T(RMS)</sub> :16A |
|                                 |      | 8:V <sub>DRM</sub> /V <sub>RRM</sub> ≥800V |    |                          |

## PACKAGE MECHANICAL DATA

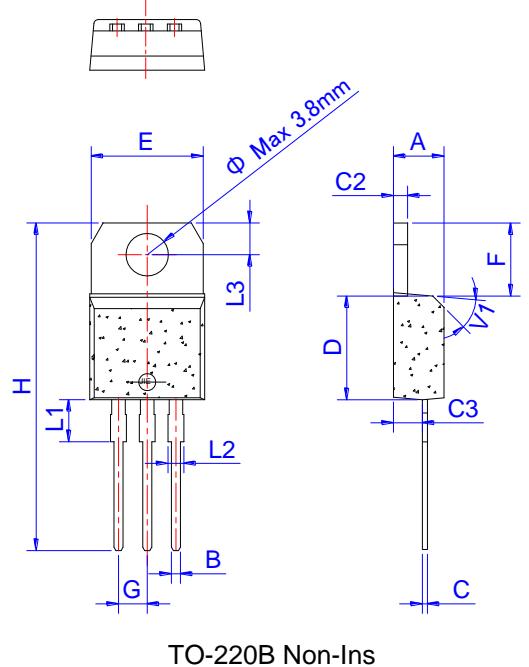


| Ref. | Dimensions  |      |      |        |       |       |
|------|-------------|------|------|--------|-------|-------|
|      | Millimeters |      |      | Inches |       |       |
|      | Min.        | Typ. | Max. | Min.   | Typ.  | Max.  |
| A    | 4.40        |      | 4.80 | 0.173  |       | 0.189 |
| B    | 0.74        | 0.80 | 0.83 | 0.029  | 0.031 | 0.033 |
| C    | 0.48        |      | 0.75 | 0.019  |       | 0.030 |
| C2   | 2.40        |      | 2.70 | 0.094  |       | 0.106 |
| C3   | 2.60        |      | 3.00 | 0.102  |       | 0.118 |
| D    | 8.80        |      | 9.30 | 0.346  |       | 0.366 |
| E    | 9.70        |      | 10.3 | 0.382  |       | 0.406 |
| F    | 6.40        |      | 7.00 | 0.252  |       | 0.276 |
| G    |             | 2.54 |      |        | 0.1   |       |
| H    | 28.0        |      | 29.8 | 1.102  |       | 1.173 |
| L1   |             | 3.63 |      |        | 0.143 |       |
| L2   | 1.14        |      | 1.70 | 0.045  |       | 0.067 |
| L3   |             | 3.30 |      |        | 0.130 |       |
| V1   |             | 45°  |      |        | 45°   |       |

## PACKAGE MECHANICAL DATA

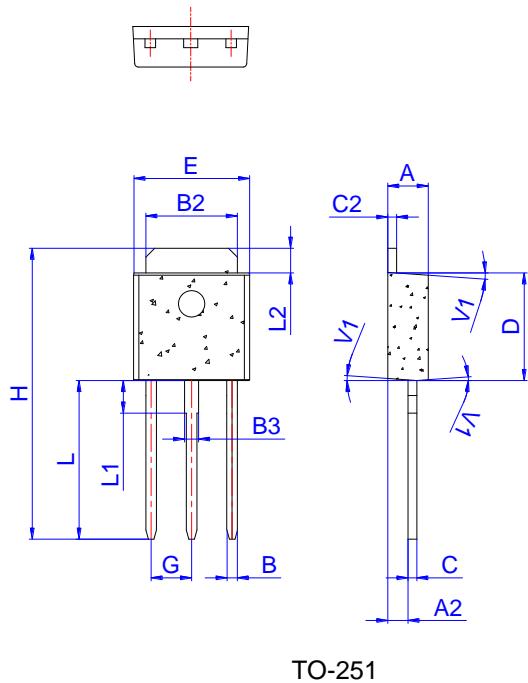


| Ref. | Dimensions  |      |      |        |       |       |
|------|-------------|------|------|--------|-------|-------|
|      | Millimeters |      |      | Inches |       |       |
|      | Min.        | Typ. | Max. | Min.   | Typ.  | Max.  |
| A    | 4.40        |      | 4.60 | 0.173  |       | 0.181 |
| B    | 0.61        |      | 0.88 | 0.024  |       | 0.035 |
| C    | 0.46        |      | 0.70 | 0.018  |       | 0.028 |
| C2   | 1.21        |      | 1.32 | 0.048  |       | 0.052 |
| C3   | 2.40        |      | 2.72 | 0.094  |       | 0.107 |
| D    | 8.60        |      | 9.70 | 0.339  |       | 0.382 |
| E    | 9.80        |      | 10.4 | 0.386  |       | 0.409 |
| F    | 6.55        |      | 6.95 | 0.258  |       | 0.274 |
| G    |             | 2.54 |      |        | 0.1   |       |
| H    | 28.0        |      | 29.8 | 1.102  |       | 1.173 |
| L1   |             | 3.75 |      |        | 0.148 |       |
| L2   | 1.14        |      | 1.70 | 0.045  |       | 0.067 |
| L3   | 2.65        |      | 2.95 | 0.104  |       | 0.116 |
| V1   |             | 45°  |      |        | 45°   |       |

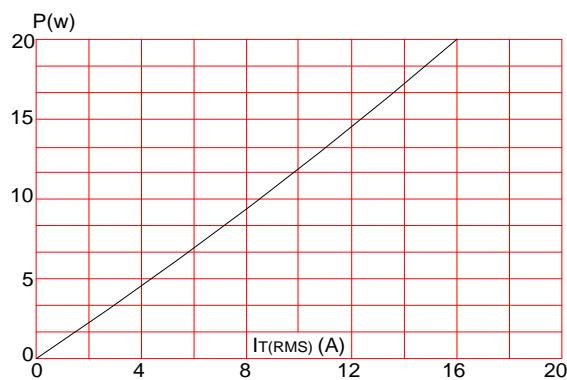


| Ref. | Dimensions  |      |      |        |       |       |
|------|-------------|------|------|--------|-------|-------|
|      | Millimeters |      |      | Inches |       |       |
|      | Min.        | Typ. | Max. | Min.   | Typ.  | Max.  |
| A    | 4.40        |      | 4.60 | 0.173  |       | 0.181 |
| B    | 0.61        |      | 0.88 | 0.024  |       | 0.035 |
| C    | 0.46        |      | 0.70 | 0.018  |       | 0.028 |
| C2   | 1.21        |      | 1.32 | 0.048  |       | 0.052 |
| C3   | 2.40        |      | 2.72 | 0.094  |       | 0.107 |
| D    | 8.60        |      | 9.70 | 0.339  |       | 0.382 |
| E    | 9.60        |      | 10.4 | 0.378  |       | 0.409 |
| F    | 6.20        |      | 6.60 | 0.244  |       | 0.260 |
| G    |             | 2.54 |      |        | 0.1   |       |
| H    | 28.0        |      | 29.8 | 1.102  |       | 1.173 |
| L1   |             | 3.75 |      |        | 0.148 |       |
| L2   | 1.14        |      | 1.70 | 0.045  |       | 0.067 |
| L3   | 2.65        |      | 2.95 | 0.104  |       | 0.116 |
| V1   |             | 45°  |      |        | 45°   |       |

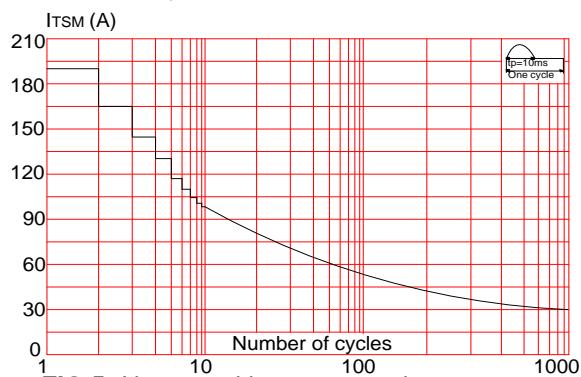
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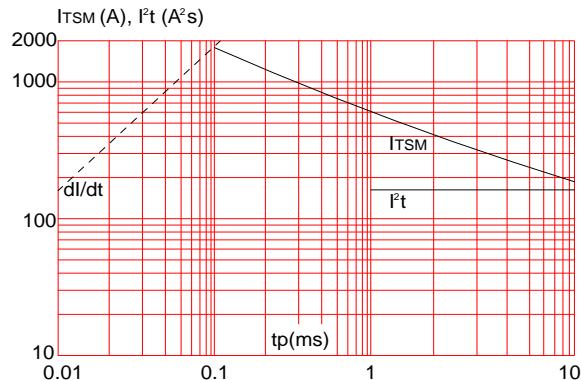
**FIG.1** Maximum power dissipation versus RMS on-state current



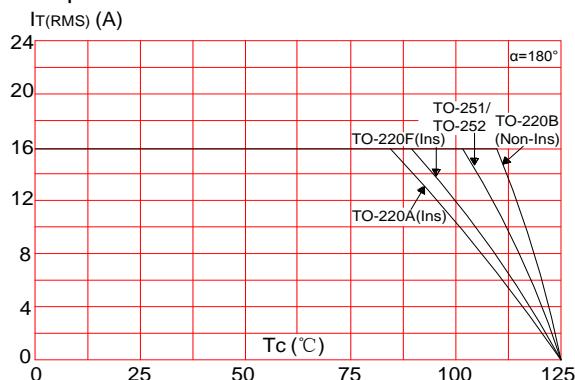
**FIG.3:** Surge peak on-state current versus number of cycles



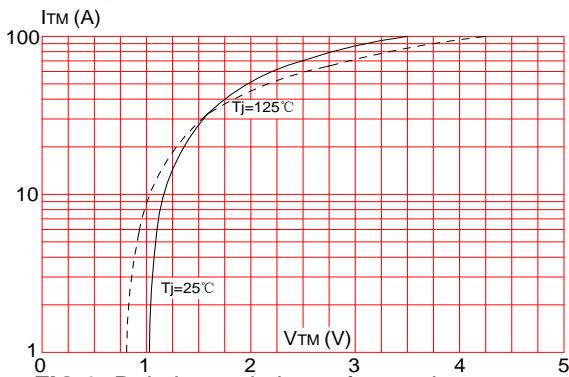
**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $tp < 10\text{ms}$ , and corresponding value of  $I^2t$  ( $dl/dt < 50\text{A}/\mu\text{s}$ )



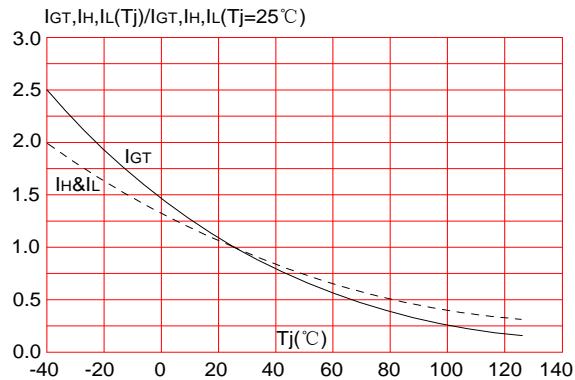
**FIG.2:** RMS on-state current versus case temperature



**FIG.4:** On-state characteristics (maximum values)



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature



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